# High Accuracy, Low Power, Barometric Pressure

# and Temperature Sensor IC

#### **GENERAL INFORMATION**

The ICP-10111 pressure sensor family is based on MEMS capacitive technology which provides ultra-low noise at the lowest power, enabling industry leading relative accuracy, sensor throughput, and temperature stability. The pressure sensor can measure pressure differences with an accuracy of  $\pm 1$  Pa, enabling altitude measurement differentials as small as 8.5 cm, less than the height of a single stair step.

Consuming only 1.3  $\mu$ A @1 Hz, available in footprint of 2 mm x 2.5 mm x 0.92 mm, the ICP-10111 is ideally suited for mobile phones, wearable fitness monitoring, drones, and battery powered IoT.

The ICP-10111 offers an industry leading temperature coefficient offset of ±0.5 Pa/°C. The combination of high accuracy, low power, temperature stability, waterproofing in a small footprint enables higher performance barometric pressure sensing for sports activity identification, mobile indoor/outdoor navigation, and altitude-hold in drones.

### **DEVICE INFORMATION**

PART NUMBER	PACKAGE	LID OPENING	MSL**
ICP-10111*	2x2.5x0.92mm LGA-8L	1-Hole	1

\* Denotes RoHS and Green-Compliant Package

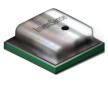
\*\* Moisture Sensitivity Level of the package

### **APPLICATIONS**

- Altitude Control of Drones and Flying Toys
- Mobile Phones
- Virtual Reality and Gaming Equipment
- Indoor/Outdoor Navigation (dead-reckoning, floor/elevator/step detection)
- Vertical velocity monitoring
- Leisure, Sports, and Fitness Activity Identification
- Weather Forecasting

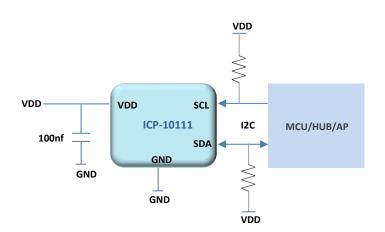
#### FEATURES

- Pressure operating range: 30 to 110 kPa
- Noise and current consumption
  - 0.4 Pa @ 10.4 μA (ULN mode)
    - 0.8 Pa @ 5.2 μA (LN mode)
  - 3.2 Pa @ 1.3 μA (LP mode)
- Pressure Sensor Relative Accuracy: ±1 Pa for any 10 hPa change over 950 hPa-1050 hPa at 25°C
- Pressure Sensor Absolute Accuracy: ±1 hPa over 950 hPa-1050 hPa, 0°C to 65°C
- Pressure Sensor Temperature Coefficient Offset: ±0.5 Pa/°C over 25°C to 45°C at 100 kPa
- Temperature Sensor Absolute Accuracy: ±0.4°C
- Temperature operating range: -40 °C to 85 °C
- Host Interface: I<sup>2</sup>C at up to 400 kHz
- Single Supply voltage: 1.8V ±5%
- RoHS and Green compliant



1-Hole Lid Opening ICP-10111

### **BLOCK DIAGRAM**



InvenSense, a TDK Group Company 1745 Technology Drive, San Jose, CA 95110 U.S.A +1(408) 988–7339 invensense.tdk.com Document Number: DS-000177 Revision: 1.3 Release Date: 05/03/2021

# ICP-10111

# TABLE OF CONTENTS

	Gene	ERAL INFORMATION	1
	Devi	ICE INFORMATION	1
	Appl	LICATIONS	1
	Feat	rures	1
	BLOC	CK DIAGRAM	1
1	IN	NTRODUCTION	5
	1.1	Purpose and Scope	5
	1.2	PRODUCT OVERVIEW	
2	PI	RESSURE AND TEMPERATURE SENSOR SPECIFICATIONS	6
	2.1	OPERATION RANGES	6
	2.2	OPERATION MODES	6
	2.3	Pressure Sensor Specifications	7
	2.4	TEMPERATURE SENSOR SPECIFICATIONS	7
	2.5	RECOMMENDED OPERATION CONDITIONS	7
3	EI	LECTRICAL SPECIFICATIONS	8
	3.1	Electrical Characteristics	8
	3.2	Absolute Maximum Ratings	
	3.3	Sensor System Timing	
	3.4	I <sup>2</sup> C TIMING CHARACTERIZATION	
4	Α	PPLICATIONS INFORMATION	11
	4.1	INTERFACE SPECIFICATIONS	11
	4.2	PIN OUT DIAGRAM AND SIGNAL DESCRIPTION	
		CP-10111: 2x2.5x0.92 mm 8-pin LGA	
	4.3	Typical Operating Circuit	
	4.4	BILL OF MATERIALS FOR EXTERNAL COMPONENTS	
5	о	PPERATION AND COMMUNICATION	14
	5.1	Power-Up and Communication Start	14
	5.2	Measurement Commands	14
	5.3	Starting a Measurement	
	5.4	Sensor Behavior During Measurement	14
	5.5	Readout of Measurement Results	14
	5.6	Soft Reset	15
	5.7	Read-out of ID Register	15
	5.8	CHECKSUM CALCULATION	15
	5.9	Conversion of Signal Output	16
	5.10		
	5.11		
	5.12	2 Sample Code: Conversion Formula (example Python syntax)	19
	5.13	3 SAMPLE CODE: USING CONVERSION FORMULA (EXAMPLE PYTHON SYNTAX)	20
	5.14		
6	A	SSEMBLY	22
	6.1	Implementation and Usage Recommendations	22
	Sc	oldering	22
		hemical Exposure and Sensor Protection	
7	P	ACKAGE DIMENSIONS	23

# ICP-10111

8	PART NUMBER PART MARKINGS	26
9	TAPE & REEL SPECIFICATION	27
10	ORDERING GUIDE	28
11	REFERENCES	29
12	REVISION HISTORY	30

### **LIST OF FIGURES**

Figure 1. Digital I/O Pads Timing	10
Figure 2. Pin Out Diagram for ICP-10111 2 mm x 2.5 mm x 0.92 mm LGA	11
Figure 3. ICP-10111 Application Schematic	12
Figure 4. Example: Typical Application Circuit	12
Figure 5. Communication Data Sequences	21
Figure 6. ICP-10111 Package Diagrams	23
Figure 7. ICP-10111 recommended PCB land pattern	24
Figure 8. Part Number Part Markings for 2x2.5mm (ICP-10111)	26
Figure 9. ICP-10111 Tape Dimensions	
Figure 10. ICP-10111 Tape and Reel Drawing	

### **LIST OF TABLES**

Table 2. Operation Modes.6Table 3. Pressure Sensor Specifications7Table 4. Temperature Sensor Specifications7Table 5. Electrical Specifications8Table 6. Absolute Maximum Ratings9Table 7. System Timing Specifications9Table 8. I²C Parameters Specification10Table 9. Signal Descriptions11Table 10. Bill of Materials13Table 11. ICP-10111 I²C Device Address14Table 12. Measurement Commands15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24Table 18. Part Number Part Markings26	Table 1. Operation Ranges	6
Table 4. Temperature Sensor Specifications7Table 5. Electrical Specifications8Table 6. Absolute Maximum Ratings9Table 7. System Timing Specifications9Table 8. I²C Parameters Specification10Table 9. Signal Descriptions11Table 10. Bill of Materials13Table 11. ICP-10111 I²C Device Address14Table 13. Soft Reset Commands15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24	Table 2. Operation Modes	6
Table 5. Electrical Specifications8Table 6. Absolute Maximum Ratings9Table 7. System Timing Specifications9Table 8. I²C Parameters Specification10Table 9. Signal Descriptions11Table 10. Bill of Materials13Table 11. ICP-10111 I²C Device Address14Table 12. Measurement Commands14Table 13. Soft Reset Command15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24		
Table 6. Absolute Maximum Ratings9Table 7. System Timing Specifications9Table 8. I²C Parameters Specification10Table 9. Signal Descriptions11Table 10. Bill of Materials13Table 11. ICP-10111 I²C Device Address14Table 12. Measurement Commands14Table 13. Soft Reset Command15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24	Table 4. Temperature Sensor Specifications	7
Table 7. System Timing Specifications9Table 8. I²C Parameters Specification10Table 9. Signal Descriptions11Table 10. Bill of Materials13Table 11. ICP-10111 I²C Device Address14Table 12. Measurement Commands14Table 13. Soft Reset Command15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24	Table 5. Electrical Specifications	8
Table 8. I²C Parameters Specification10Table 9. Signal Descriptions11Table 10. Bill of Materials13Table 11. ICP-10111 I²C Device Address14Table 12. Measurement Commands14Table 13. Soft Reset Command15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24	Table 6. Absolute Maximum Ratings	9
Table 8. I²C Parameters Specification10Table 9. Signal Descriptions11Table 10. Bill of Materials13Table 11. ICP-10111 I²C Device Address14Table 12. Measurement Commands14Table 13. Soft Reset Command15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24	Table 7. System Timing Specifications	9
Table 10. Bill of Materials13Table 11. ICP-10111 I²C Device Address14Table 12. Measurement Commands14Table 13. Soft Reset Command15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24	Table 8. I <sup>2</sup> C Parameters Specification	10
Table 10. Bill of Materials13Table 11. ICP-10111 I²C Device Address14Table 12. Measurement Commands14Table 13. Soft Reset Command15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24	Table 9. Signal Descriptions	11
Table 12. Measurement Commands14Table 13. Soft Reset Command15Table 14. Read-Out Command of ID Register15Table 15. 16-bit ID Structure15Table 16. ICP-10111 I²C CRC Properties16Table 17. ICP-10111 Package Dimensions24	Table 10. Bill of Materials	
Table 13. Soft Reset Command       15         Table 14. Read-Out Command of ID Register       15         Table 15. 16-bit ID Structure       15         Table 16. ICP-10111 I <sup>2</sup> C CRC Properties       16         Table 17. ICP-10111 Package Dimensions       24	Table 11. ICP-10111 I <sup>2</sup> C Device Address	14
Table 14. Read-Out Command of ID Register       15         Table 15. 16-bit ID Structure       15         Table 16. ICP-10111 I <sup>2</sup> C CRC Properties       16         Table 17. ICP-10111 Package Dimensions       24		
Table 15. 16-bit ID Structure       15         Table 16. ICP-10111 I <sup>2</sup> C CRC Properties       16         Table 17. ICP-10111 Package Dimensions       24	Table 13. Soft Reset Command	15
Table 16. ICP-10111 I <sup>2</sup> C CRC Properties       16         Table 17. ICP-10111 Package Dimensions       24	Table 14. Read-Out Command of ID Register	
Table 17. ICP-10111 Package Dimensions	Table 15. 16-bit ID Structure	
Table 17. ICP-10111 Package Dimensions       24         Table 18. Part Number Part Markings       26		
Table 18. Part Number Part Markings    26	Table 17. ICP-10111 Package Dimensions	24
	Table 18. Part Number Part Markings	

## **1** INTRODUCTION

### 1.1 PURPOSE AND SCOPE

This document is a preliminary product specification, providing a description, specifications, and design related information for the ICP-10111 Pressure Sensor.

Specifications are subject to change without notice. Final specifications will be updated based upon characterization of production silicon.

### **1.2 PRODUCT OVERVIEW**

The ICP-10111 is an ultra-low power, low noise, digital output barometric pressure and temperature sensor IC. It is based on an innovative MEMS capacitive pressure sensor technology that can measure pressure differences with an accuracy of ±1 Pa at the industry's lowest power. The high accuracy MEMS capacitive pressure sensor is capable of measuring altitude differentials down to 8.5 cm without the penalty of increased power consumption or reduced sensor throughput.

The capacitive pressure sensor has a  $\pm 1$  hPa absolute accuracy over its full range of 300 hPa -1100 hPa. The pressure sensor has an embedded temperature sensor and 400 kHz l<sup>2</sup>C bus for communication. For power-critical applications, the ICP-10111 features a low power mode of 1.3  $\mu$ A at a noise of 3.2 Pa or for high performance applications, it features a low noise mode of 0.8 Pa while only consuming 5.2  $\mu$ A.

The ICP-10111 also offers industry leading temperature stability of the pressure sensor with a temperature coefficient offset of  $\pm 0.5$  Pa/°C. The high accuracy, temperature stability, and market leading low power consumption of 1.3  $\mu$ A @1 Hz offered by ICP-10111 makes it ideally suited for applications such as mobile phones, drone flight control and stabilization, indoor/outdoor navigation (elevator, floor, and stair step detection), sports and fitness activity monitoring, and battery-powered IoT.

# **2 PRESSURE AND TEMPERATURE SENSOR SPECIFICATIONS**

### 2.1 OPERATION RANGES

The sensor shows best performance when operated within the recommended temperature and pressure range (hereafter called normal conditions) of  $0^{\circ}C - 45^{\circ}C$  and 95 kPa – 105 kPa, respectively. The following ranges are defined for the device:

OPERATION RANGE	PRESSURE (KPA)	TEMPERATURE (°C)
Normal	95 to 105	0 to 45
Extended	30 to 110	-20 to 65
Maximum	25 to 115	-40 to 85

#### Table 1. Operation Ranges

### **2.2 OPERATION MODES**

The sensor can be operated in up to four different measurement modes to satisfy different requirements for power consumption vs. noise, accuracy and measurement frequency. An overview of the operation modes is given in Table 2.

PARAMETER	CONDITIONS	SENSOR MODE	ТҮР	MAX	UNITS	NOTES
	Time between sending last bit of	Low Power (LP)	1.6	1.8		1
		Normal (N)	5.6	6.3		1
Conversion Time	measurement command, and sensor data ready for	Low Noise (LN)	20.8	23.8	ms	1
	measurement	Ultra Low Noise (ULN)	83.2	94.5		1
		Low Power (LP)	1.3			
Current	Normal (N) 2.6	2.6				
	1 Hz ODR	Low Noise (LN)	5.2		μΑ	
Consumption		Ultra Low Noise (ULN)	10.4			
		Low Power (LP)	3.2			
Pressure RMS Noise		Normal	1.6			
	Valid for P = 100 kPa, T = 25°C, and U = 1.8V	Low Noise (LN)	0.8		Ра	
	anu 0 – 1.8v	Ultra Low Noise (ULN)	0.4			

#### **Table 2. Operation Modes**

#### Notes:

1. Guaranteed by design.

Low Power modes supports ODR greater than 500 Hz while the Low Noise mode provides industry leading RMS noise at a fast 40 Hz ODR. Further decrease in noise may be achieved by software oversampling and filtering through customer's software implementation or custom TDK-InvenSense operation modes available upon request.

### 2.3 PRESSURE SENSOR SPECIFICATIONS

Pressure sensor specifications are given in Table 3. Default conditions of 25 °C and 1.8V supply voltage apply, unless otherwise stated.

PARAMETER	CONDITIONS	ТҮР	UNITS	NOTES
Absolute Accuracy	Normal range	±1	hPa	1, 3
Absolute Acculacy	Extended range	±1.5	IIFa	1, 5
	Any step ≤ 1 kPa, 25 °C	±1		2
Relative Accuracy	Any step ≤ 10 kPa, 25 °C	±3	Ра	3
Long-term drift	Normal Range	±35	Pa/y	
During 1 year	Extended Range	±40	Pa/y	
Solder drift		0.5	hPa	1, 2, 4
Temperature coefficient offset	P = 100 kPa	±0.5	Pa/°C	3
remperature coefficient offset	25°C 45°C	±0.5	Pd/ C	3
Resolution Maximum range		0.01	Ра	

#### **Table 3. Pressure Sensor Specifications**

#### Notes:

- 1. Absolute accuracy may be improved through One Point Calibration.
- 2. Sensor accuracy post Solder reflow may be improved through One Point Calibration.
- 3. Parameter specifications shown are component-level. They may be different at the board-level and may depend on PCB characteristics including but not limited to PCB material, number of layers, PCB thickness. They may also depend on usage conditions.
- 4. Specification value is based on PCBs with no solder mask under the device. Specification value may depend on PCB characteristics including but not limited to PCB material, number of layers, PCB thickness. It may also depend on usage conditions.

### 2.4 TEMPERATURE SENSOR SPECIFICATIONS

Specifications of the temperature sensor are shown in Table 4.

PARAMETER	CONDITIONS	ТҮР	UNITS
Absolute Accuracy	Extended range	±0.4	°C
Repeatability	Extended range	±0.1	°C
Resolution	Maximum range	0.01	°C
Long-term drift	Normal range	Normal range <0.04	

**Table 4. Temperature Sensor Specifications** 

### 2.5 RECOMMENDED OPERATION CONDITIONS

The pressure sensor exhibits best performance when operated within the normal pressure and temperature range  $0^{\circ}C < T < 45^{\circ}C$  and 95 kPa < P < 105 kPa.

Injected photo current due to strong light sources can influence the sensor performance and should be avoided to guarantee best operation.

The sensor should not be exposed to high mechanical stress, the resulting deformation of the package can alter internal dimensions and therefore falsify the sensor signal. Solder reflow may affect device performance. One-point calibration can improve the sensor accuracy post solder reflow.

# **3** ELECTRICAL SPECIFICATIONS

### **3.1 ELECTRICAL CHARACTERISTICS**

Default conditions of 25 °C and 1.8V supply voltage apply to values in Table 5, unless otherwise stated.

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	ΜΑΧ	UNITS	COMMENTS
Supply voltage	V <sub>DD</sub>		1.71	1.8	1.89	v	
Power-up/down level	V <sub>POR</sub>	Static power supply	1.0	1.25	1.5	v	
Supply Ramp Time	T <sub>ramp</sub>	Monotonic ramp. Ramp rate is 10% to 90% of the final value	0.01		100	ms	
		Idle state	-	1.0	2.5	μA	
Supply current	I <sub>DD</sub>	Measurement	-	210	300	μΑ	Current consumption while sensor is measuring.
			-	1.3	-	μΑ	Current consumption in continuous operation @ 1 Hz ODR in LP Mode
		Average	-	5.2	-	μΑ	Current consumption in continuous operation @1 Hz ODR in LN Mode
Low level input voltage	VIL		0	-	$0.3 V_{DD}$	v	
High level input voltage	V <sub>IH</sub>		$0.7  V_{\text{DD}}$	-	V <sub>DD</sub>	v	
Low level output voltage	V <sub>OL</sub>	0 < IOL < 3 mA	-	-	$0.2 V_{\text{DD}}$	v	
Output Sink Current		V <sub>OL</sub> = 0.4V	3.1	4.1	-	mA	
	I <sub>OL</sub>	V <sub>OL</sub> = 0.6V	3.5	4.5	-	mA	

**Table 5. Electrical Specifications** 

### 3.2 ABSOLUTE MAXIMUM RATINGS

Stress levels beyond those listed in Table 6 may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions cannot be guaranteed. Exposure to the absolute maximum rating conditions for extended periods may affect the reliability of the device.

PARAMETER	RATING
Supply voltage, VDD	-0.3V to 2.16V
Supply Voltage, SCL & SDA	-0.3V to VDD 0.3V
Operating temperature range	-40°C to 85°C
Storage temperature range	-40°C to 125°C
ESD HBM	2.0 kV
ESD CDM	250V
Latch up, JESD78 Class II, 85°C	100 mA
Overpressure	>600kPa

#### Table 6. Absolute Maximum Ratings

### 3.3 SENSOR SYSTEM TIMING

Default conditions of 25°C and 1.8V supply voltage apply to typ. values listed in Table 7, unless otherwise stated. Max. values apply over the specified operating range of VDD and over the operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS	COMMENTS
Power-up time	t <sub>PU</sub>	After hard reset, $V_{DD} \ge V_{POR}$	-	170	-	μs	Time between $V_{\text{DD}}$ reaching $V_{\text{PU}}$ and sensor entering idle state
Soft reset time	t <sub>sr</sub>	After soft reset	-	170	-	μs	Time between ACK of soft reset command and sensor entering idle state
Measurement duration	t <sub>MEAS</sub>	LN Mode	-	20.8	23.8	ms	Duration for a pressure and temperature measurement

**Table 7. System Timing Specifications** 

### 3.4 I<sup>2</sup>C TIMING CHARACTERIZATION

Default conditions of 25°C and 1.8V supply voltage apply to values in Table 8, unless otherwise stated.

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
SCL clock frequency	f <sub>SCL</sub>		0	-	400	kHz
Hold time (repeated) START condition	t <sub>hd;sta</sub>	After this period, the first clock pulse is generated	0.6	-	-	μs
LOW period of the SCL clock	$t_{\text{LOW}}$		1.3	-	-	μs
HIGH period of the SCL clock	t <sub>HIGH</sub>		0.6	-	-	μs
Set-up time for a repeated START condition	t <sub>su;sta</sub>		0.6	-	-	μs
SDA hold time	t <sub>HD;DAT</sub>		0	-	-	μs
SDA set-up time	t <sub>su;dat</sub>		100	-	-	ns
SCL/SDA rise time	t <sub>R</sub>		20	-	300	ns
SCL/SDA fall time	t <sub>F</sub>		-	-	300	ns
SDA valid time	t <sub>vd;dat</sub>		-	-	0.9	μs
Set-up time for STOP condition	t <sub>su;sto</sub>		0.6	-	-	μs
Capacitive load on bus line	C <sub>B</sub>		-	-	400	pF

#### Table 8. I<sup>2</sup>C Parameters Specification

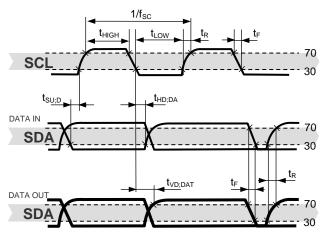


Figure 1. Digital I/O Pads Timing

### **4** APPLICATIONS INFORMATION

### 4.1 INTERFACE SPECIFICATIONS

The ICP-10111 supports I<sup>2</sup>C fast mode, SCL clock frequency from 0 to 400 kHz.

### 4.2 PIN OUT DIAGRAM AND SIGNAL DESCRIPTION

### ICP-10111: 2x2.5x0.92 mm 8-pin LGA

PIN NUMBER	PIN NAME	DESCRIPTION
1	GND	Connect to Ground
2	RESV	No Internal Connection: Can connect to VDD/V <sub>DDIO</sub> /GND/NC
3	SDA	I <sup>2</sup> C Serial Data
4	SCL	I <sup>2</sup> C Serial Clock
5	RESV	Connect to Ground
6	RESV	No Internal Connection: Can connect to VDD/V <sub>DDIO</sub> /GND/NC
7	GND	Connect to Ground
8	VDD	Power Supply VDD



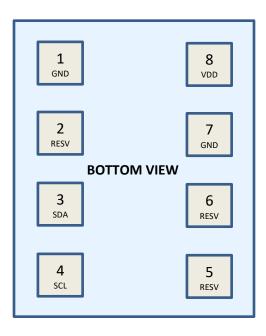
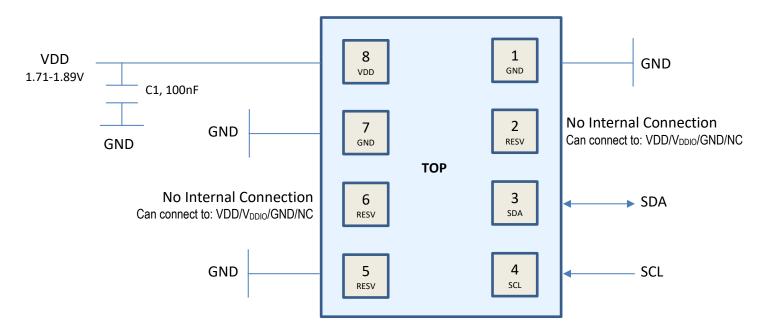


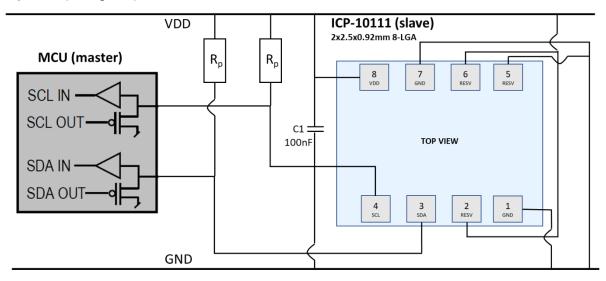
Figure 2. Pin Out Diagram for ICP-10111 2 mm x 2.5 mm x 0.92 mm LGA

### 4.3 TYPICAL OPERATING CIRCUIT



#### Figure 3. ICP-10111 Application Schematic

Power supply pins supply voltage (Vdd) and ground (Vss) must be decoupled with a 100 nF capacitor that shall be placed as close to the sensor as possible (see Figure 4).



#### Figure 4. Example: Typical Application Circuit

SCL is used to synchronize the communication between the microcontroller and the sensor. The master must keep the clock frequency within 0 to 400 kHz as specified in Table 8.

The SDA pin is used to transfer data in and out of the sensor. For safe communication, the timing specifications defined in the I2C manual must be met.

To avoid signal contention, the microcontroller must only drive SDA and SCL low. External pull-up resistors (i.e.  $10 \text{ k}\Omega$ ) are required to pull the signal high. For dimensioning resistor sizes, user should also consider bus capacity requirements. It should be noted that pull-up resistors may be included in I/O circuits of microcontrollers.

User should refer to AN-000140 "TDK-InvenSense Pressure Sensor PCB Design Guidelines" for PCB guidelines and sensor integration.

### 4.4 BILL OF MATERIALS FOR EXTERNAL COMPONENTS

COMPONENT	LABEL	SPECIFICATION	QUANTITY
VDD Bypass Capacitor	C1	Ceramic, X7R, 100 nF ±10%	1

Table 10. Bill of Materials

## 5 OPERATION AND COMMUNICATION

All commands and memory locations of the ICP-10111 are mapped to a 16-bit address space which can be accessed via the I<sup>2</sup>C protocol.

ICP-10111	BINARY	DECIMAL	HEXADECIMAL
I <sup>2</sup> C address	110'0011	99	0x63

#### Table 11. ICP-10111 I<sup>2</sup>C Device Address

#### 5.1 POWER-UP AND COMMUNICATION START

Upon VDD reaching the power-up voltage level V<sub>POR</sub>, the ICP-10111 enters idle state after a duration of t<sub>PU</sub>. In idle state, the ICP-10111 is ready to receive commands from the master (microcontroller).

Each transmission sequence begins with START condition (S) and ends with an (optional) STOP condition (P) as described in the I<sup>2</sup>C-bus specification. Whenever the sensor is powered up, but not performing a measurement or communicating, it automatically enters idle state for energy saving.

### 5.2 MEASUREMENT COMMANDS

The ICP-10111 provides the possibility to define the sensor behavior during measurement as well as the transmission sequence of measurement results. These characteristics are defined by the appropriate measurement command.

Each measurement command triggers both a temperature and a pressure measurement.

OPERATION MODE	<b>TRANSMIT T FIRST</b>	<b>TRANSMIT P FIRST</b>
Low Power (LP)	0x609C	0x401A
Normal (N)	0x6825	0x48A3
Low Noise (LN)	0x70DF	0x5059
Ultra-Low Noise (ULN)	0x7866	0x58E0

Table 12. Measurement Commands

### 5.3 STARTING A MEASUREMENT

A measurement communication sequence consists of a START condition followed by the I<sup>2</sup>C header with the 7-bit I<sup>2</sup>C device address and a write bit (write W: '0', 8-bit word including I<sup>2</sup>C header: 0xC6). The sensor indicates the proper reception of a byte by pulling the SDA pin low (ACK bit) after the falling edge of the 8th SCL clock. Then the sensor is ready to receive a 16-bit measurement command. Again, the ICP-10111 acknowledges the proper reception of each byte with ACK condition. A complete measurement cycle is presented in Figure 5.

With the acknowledgement of the measurement command, the ICP-10111 starts measuring pressure and temperature.

### 5.4 SENSOR BEHAVIOR DURING MEASUREMENT

In general, the sensor does not respond to any I<sup>2</sup>C activity during measurement, i.e. I<sup>2</sup>C read and write headers are not acknowledged (NACK).

### 5.5 READOUT OF MEASUREMENT RESULTS

After a measurement command has been issued and the sensor has completed the measurement, the master can read the measurement results by sending a START condition followed by an I<sup>2</sup>C read header (8-bit word including I<sup>2</sup>C header: 0xC7). The sensor will acknowledge the reception of the read header and send the measured data in the specified order to the master. The MSB of the corresponding data is always transmitted first. Temperature data is transmitted in two 8-bit words and pressure data is transmitted in four 8-bit words. Regarding the pressure data, only the first three words MMSB, MLSB and LMSB contain information about the ADC pressure value *p\_dout*. Therefore, for retrieving the ADC pressure value, LLSB must be disregarded:

 $p\_dout = MMSB \ll 16 | MLSB \ll 8 | LMSB.$ 

Two bytes of data are always followed by one byte CRC checksum, for calculation see section 5.8. Each byte must be acknowledged by the microcontroller with an ACK condition for the sensor to continue sending data. If the ICP-10111 does not receive an ACK from the master after any byte of data, it will not continue sending data.

Whether the sensor sends out pressure or temperature data first depends on the measurement command that was sent to the sensor to initiate the measurement (see Table 12).

The I<sup>2</sup>C master can abort the read transfer with a NACK condition after any data byte if it is not interested in subsequent data, e.g. the CRC byte or the second measurement result, to save time.

### 5.6 SOFT RESET

The ICP-10111 provides a soft reset mechanism that forces the system into a well-defined state without removing the power supply. If the system is in idle state (i.e. if no measurement is in progress) the soft reset command will be accepted by ICP-10111. This triggers the sensor to reset all internal state machines and reload calibration data from the memory.

COMMAND	HEXADECIMAL CODE	BINARY CODE
Soft reset	0x805D	1000'0000'0101'1101

Table 13. Soft Reset Command

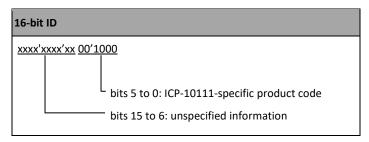
### 5.7 READ-OUT OF ID REGISTER

The ICP-10111 has an ID register which contains a specific product code. The read-out of the ID register can be used to verify the presence of the sensor and proper communication. The command to read the ID register is shown in Table 14.

COMMAND	HEXADECIMAL CODE	BINARY CODE
Read ID register	0xEFC8	1110'1111'1100'1000

#### Table 14. Read-Out Command of ID Register

It needs to be sent to the ICP-10111 after an I<sup>2</sup>C write header. After the ICP-10111 has acknowledged the proper reception of the command, the master can send an I<sup>2</sup>C read header and the ICP-10111 will submit the 16-bit ID followed by 8 bits of CRC. The structure of the ID is described in Table 15. Bits 15:6 of the ID contain unspecified information (marked as "x"), which may vary from sensor to sensor, while bits 5:0 contain the ICP-10111 specific product code.



#### Table 15. 16-bit ID Structure

### 5.8 CHECKSUM CALCULATION

The 8-bit CRC checksum transmitted after each data word is generated by a CRC algorithm with the properties displayed in Table 16. The CRC covers the contents of the two previously transmitted data bytes.

PROPERTY	VALUE
Name	CRC-8
Width	8 bits
Polynomial	0x31 (x <sup>8</sup> + x <sup>5</sup> + x <sup>4</sup> + 1)
Initialization	0xFF
Reflect input	false
Reflect output	false
Final XOR	0x00
Examples	CRC(0x00) = 0xAC CRC(0xBEEF) = 0x92

#### Table 16. ICP-10111 I<sup>2</sup>C CRC Properties

### 5.9 CONVERSION OF SIGNAL OUTPUT

Pressure measurement data is always transferred as 4 8-bit words; temperature measurement data is always transferred as two 8bit words. Please see section 5.5 for more details.

Temperature measurement values *t\_dout* are linearized by the ICP-10111 and must be calculated to °C by the user via the following formula:

$$T = -45^{\circ}\text{C} + \frac{175^{\circ}\text{C}}{2^{16}} \times t_{dout}.$$

For retrieving physical pressure values in Pa the following conversion formula has to be used:

$$P = A + \frac{B}{C + p_{\text{dout}}},$$

where *p\_dout* is the sensor's raw pressure output. The converted output is compensated for temperature effects via the temperature dependent functions *A*, *B* and *C*. Besides the raw temperature output *t\_dout*, the calculation of *A*, *B* and *C* requires to access calibration parameters OTP0, OTP1, OTP2, OTP3 stored in the OTP of the sensor. Read-out of OTP parameters is described in section 5.10.

Full sample code for calculating physical pressure values is given in section 5.11. The general workflow of the conversion is done by:

- 1) Import class Invensense\_pressure\_conversion
- 2) Read out values OTPO, ..., OTP3 and save to c1, ..., c4
- 3) Create object name for an individual sensor with parameter values c1, ..., c4 name = Invensense\_pressure\_conversion ([c1,c2,c3,c4])
- 4) Get raw pressure *p\_dout* and temperature *t\_dout* data from the sensor as described in chapter 5.5.
- Call function get\_pressure: name.get\_pressure(p\_dout, t\_dout)

The sample code from section 5.13 gives an example of this workflow.

### **5.10 READ-OUT OF CALIBRATION PARAMETERS**

For converting raw pressure data to physical values, four calibration parameters have to be retrieved from the OTP of the sensor.

#### Set up of OTP read:

- 1) Send I<sup>2</sup>C write header 0xC6
- 2) Send command 0xC595 (move pointer in address register)
- 3) Send address parameter together with its CRC 0x00669C

Steps 1) – 3) can be executed on many platforms by a single  $I^2C$  write of the value 0xC59500669C.

#### **Read out parameters:**

Repeat the following procedure 4 times:

- a) Send I<sup>2</sup>C write header 0xC6
- b) Send command 0xC7F7 (incremental read-out of OTP)
- c) Send I<sup>2</sup>C read header 0xC7
- d) Read 3B (2B of data and 1B of CRC)
- e) Decode data as 16bit big endian signed integer and store result into n-th calibration parameter cn.

Steps a) to d) can be executed on many platforms by a single write 0xC7F7 to the chip address followed by a single read of 3 B from the chip address.

#### 5.11 SAMPLE CODE: EXAMPLE C SYNTAX

```
/* data structure to hold pressure sensor related parameters */
typedef struct inv_invpres
ł
 struct inv_invpres_serif serif;
 uint32_t min_delay_us;
 uint8_t pressure_en;
 uint8_t temperature_en;
  float sensor_constants[4]; // OTP values
 float p_Pa_calib[3];
 float LUT_lower;
 float LUT_upper;
 float quadr_factor;
 float offst_factor;
} inv_invpres_t;
int inv_invpres_init(struct inv_invpres * s)
ł
 short otp[4];
 read_otp_from_i2c(s, otp);
init base(s, otp);
 return 0;
}
int read_otp_from_i2c(struct inv_invpres * s, short *out)
ł
 unsigned char data_write[10];
 unsigned char data_read[10] = {0};
 int status;
 int i:
  // OTP Read mode
 data_write[0] = 0xC5;
 data_write[1] = 0x95;
 data_write[2] = 0x00;
 data_write[3] = 0x66;
 data_write[4] = 0x9C;
```

# ICP-10111

```
status = inv_invpres_serif_write_reg(&s->serif, ICC_ADDR_PRS, data_write, 5);
if (status)
    return status;

// Read OTP values
for (i = 0; i < 4; i++) {
    data_write[0] = 0xC7;
    data_write[1] = 0xF7;
    status = inv_invpres_serif_write_reg(&s->serif, ICC_ADDR_PRS, data_write, 2);
    if (status)
        return status;

status = inv_invpres_serif_read_reg(&s->serif, ICC_ADDR_PRS, data_read, 3);
if (status)
    return status;

out[i] = data_read[0]<<8 | data_read[1];
</pre>
```

```
}
return 0;
```

```
}
```

```
void init_base(struct inv_invpres * s, short *otp)
{
  int i;
  for(i = 0; i < 4; i++)</pre>
              s->sensor_constants[i] = (float)otp[i];
 s->p_Pa_calib[0] = 45000.0;
s->p_Pa_calib[1] = 80000.0;
  s->p_Pa_calib[2] = 105000.0;
  s->LUT_lower = 3.5 * (1<<20);
s->LUT_upper = 11.5 * (1<<20);</pre>
  s->quadr_factor = 1 / 16777216.0;
  s->offst_factor = 2048.0;
}
// p_LSB -- Raw pressure data from sensor
// T_LSB -- Raw temperature data from sensor
int inv_invpres_process_data(struct inv_invpres * s, int p_LSB, int T_LSB,
                                                                         float * pressure, float * temperature)
{
  float t;
  float s1, s2, s3;
  float in[3];
  float out[3];
  float A,B,C;
  t = (fLoat)(T_LSB - 32768);
  s1 = s->LUT_Lower + (float)(s->sensor_constants[0] * t * t) * s->quadr_factor;
s2 = s->offst_factor * s->sensor_constants[3] + (float)(s->sensor_constants[1] * t * t) * s->quadr_factor;
  s3 = s->LUT_upper + (float)(s->sensor_constants[2] * t * t) * s->quadr_factor;
  in[0] = s1;
  in[1] = s2;
  in[2] = s3;
  calculate_conversion_constants(s, s->p_Pa_calib, in, out);
  A = out[0];
  B = out[1];
  C = out[2];
  *pressure = A + B / (C + p_LSB);
*temperature = -45.f + 175.f/65536.f * T_LSB;
  return 0;
}
// p_Pa -- List of 3 values corresponding to applied pressure in Pa
// p_LUT -- List of 3 values corresponding to the measured p_LUT values at the applied pressures.
void calculate_conversion_constants(struct inv_invpres * s, float *p_Pa,
                                                                                                 float *p_LUT, float *out)
{
  float A,B,C;
   \begin{array}{l} C = (p\_LUT[0] * p\_LUT[1] * (p\_Pa[0] - p\_Pa[1]) + \\ p\_LUT[1] * p\_LUT[2] * (p\_Pa[1] - p\_Pa[2]) + \\ p\_LUT[2] * p\_LUT[0] * (p\_Pa[2] - p\_Pa[0])) \, / \end{array}
```



### 5.12 SAMPLE CODE: CONVERSION FORMULA (EXAMPLE PYTHON SYNTAX)

```
class InvensensePressureConversion:
```

""" Class for conversion of the pressure and temperature output of the Invensense sensor"""

```
def __init__(self, sensor_constants):
```

""" Initialize customer formula

```
Arguments:
```

```
sensor_constants -- list of 4 integers: [c1, c2, c3, c4]
```

```
....
```

```
self.sensor_constants = sensor_constants
```

```
# configuration for ICP-10111 Samples
self.p_Pa_calib = [45000.0, 80000.0, 105000.0]
self.LUT_lower = 3.5 * (2**20)
self.LUT_upper = 11.5 * (2**20)
self.quadr_factor = 1 / 16777216.0
self.offst_factor = 2048.0
```

```
def calculate_conversion_constants(self, p_Pa, p_LUT):
    """ calculate temperature dependent constants
```

```
Arguments:
```

```
p_Pa -- List of 3 values corresponding to applied pressure in Pa
p_LUT -- List of 3 values corresponding to the measured p_LUT values at the applied pressures.
"""
C = (p_LUT[0] * p_LUT[1] * (p_Pa[0] - p_Pa[1]) +
```

```
p_LUT[1] * p_LUT[2] * (p_Pa[1] - p_Pa[2]) +
p_LUT[2] * p_LUT[0] * (p_Pa[2] - p_Pa[0])) / \
(p_LUT[2] * (p_Pa[0] - p_Pa[1]) +
p_LUT[0] * (p_Pa[1] - p_Pa[2]) +
p_LUT[1] * (p_Pa[2] - p_Pa[0]))
A = (p_Pa[0] * p_LUT[0] - p_Pa[1] * p_LUT[1] - (p_Pa[1] - p_Pa[0]) * C) / (p_LUT[0] - p_LUT[1])
B = (p_Pa[0] - A) * (p_LUT[0] + C)
```

return [A, B, C]

```
def get_pressure(self, p_LSB, T_LSB):
```

""" Convert an output from a calibrated sensor to a pressure in Pa.

#### Arguments:

```
p_LSB -- Raw pressure data from sensor
T_LSB -- Raw temperature data from sensor
"""
t = T_LSB - 32768.0
s1 = self.LUT_lower + float(self.sensor_constants[0] * t * t) * self.quadr_factor
s2 = self.offst_factor * self.sensor_constants[3] + float(self.sensor_constants[1] * t * t) * self.quadr_factor
s3 = self.LUT_upper + float(self.sensor_constants[2] * t * t) * self.quadr_factor
A, B, C = self.calculate_conversion_constants(self.p_Pa_calib, [s1, s2, s3])
return A + B / (C + p_LSB)
```

[end of the pseudocode]

### 5.13 SAMPLE CODE: USING CONVERSION FORMULA (EXAMPLE PYTHON SYNTAX)

def read\_otp\_from\_i2c():

# TODO: implement read from I2C

# refer to data sheet for I2C commands to read OTP

return 1000, 2000, 3000, 4000

def read\_raw\_pressure\_temp\_from\_i2c():

# TODO: implement read from I2C

# refer to data sheet for I2C commands to read pressure and temperature return 8000000, 32000

# Sample code to read

 $from \ \ Invensense\_pressure\_conversion \ import \ \ Invensense\_pressure\_conversion$ 

# -- initialization

```
c1, c2, c3, c4 = read_otp_from_i2c()
conversion = Invensense_pressure_conversion([c1, c2, c3, c4])
```

# -- read raw pressure and temp data, calculate pressure

p, T = read\_raw\_pressure\_temp\_from\_i2c()

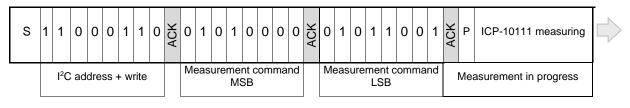
pressure = conversion.get\_pressure(p, T)

print 'Pressure: %f' % pressure

[end of the pseudocode]

### **5.14 COMMUNICATION DATA SEQUENCES**

1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27 28





29	30	31	32	33	34	35	36	37	38	39			40	41	42	43	44	45	46	47	48	49
s	1	1	0	0	0	1	1	1	NACK	Ρ	ICP-10111 measuring	ICP-10111 in idle state	s	1	1	0	0	0	1	1	1	ACK
		epea reac	l wł	nile		as.	is i			r	neasurement cont'd	measurement completed			I <sup>2</sup> C	ad	dre	SS -	+ re	ad		

50 51 52 53 54 55 56 57 58 59 60 61 62 63 64 65 66 67 68 69 70 71 72 73 74 75 76

1	0	1	0	0	0	0	1	ACK	0	0	1	1	0	0	1	1	ACK	0	0	0	1	1	1	0	0	ACK	5	
	Pı	res	sure	e M	IMS	SΒ				Ρ	res	sur	e N	1LS	В				F		ssu necl		CR( Im	С				

77 78 79 80 81 82 83 84 85 86 87 88 89 90 91 92 93 94 95 96 97 98 99 100 101 102 103

1	0	1	0	0	0	0	1	ACK	0	0	1	1	0	0	1	1	ACK	0	0	0	1	1	1	0	0	ACK	
	Ρ	res	sur	e L	MS	в				Ρ	res	sui	re L	LS	В				F	Pres ch		re ( ksu		С			

 $104\,105\,106\,107\,108\,109\,110\,111\,112\,113\,114\,115\,116\,117\,118\,119\,120\,121\,122\,123\,124\,125\,126\,127\,128\,129\,130\,131$ 

0	1	1	1	0	0	1	0	0	ACK	1	0	0	0	1	0	1	1	ACK	1	1	0	0	0	1	1	1	NACK	Ρ
	Temperature MSB							Те	mp	era	tur	e Li	SB				Те	•		ture ksu		RC						

Figure 5. Communication Data Sequences

### 6 ASSEMBLY

This section provides general guidelines for assembling TDK-InvenSense Micro Electro-Mechanical Systems (MEMS) pressure sensors.

### 6.1 IMPLEMENTATION AND USAGE RECOMMENDATIONS

### Soldering

When soldering, use the standard soldering profile IPC/JEDEC J-STD-020 with peak temperatures of 260°C. ICP-10111 may exhibit a pressure offset after soldering, some settling time may be required depending on soldering properties, PCB properties, and ambient conditions.

The ICP-10111 is an open cavity package, it is mandatory to use no-clean solder paste and no board wash should be applied.

### **Chemical Exposure and Sensor Protection**

The ICP-10111 is an open cavity package, and should not be exposed to particulates or liquids. If any type of protective coating must be applied to the circuit board, the sensor must be protected during the coating process.

# 7 PACKAGE DIMENSIONS

Package dimensions for the ICP-10110 & ICP-10111:

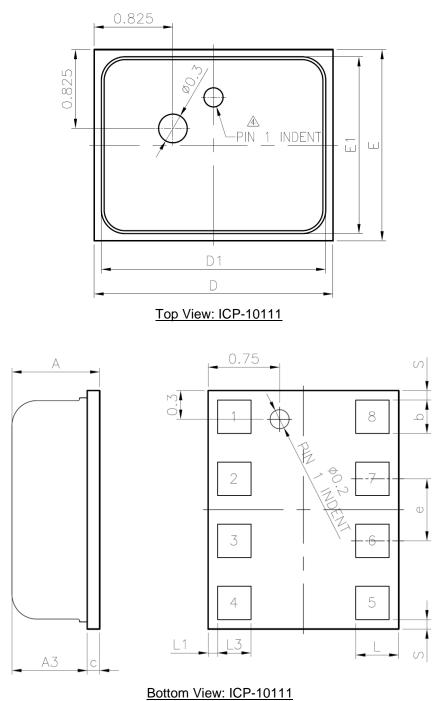


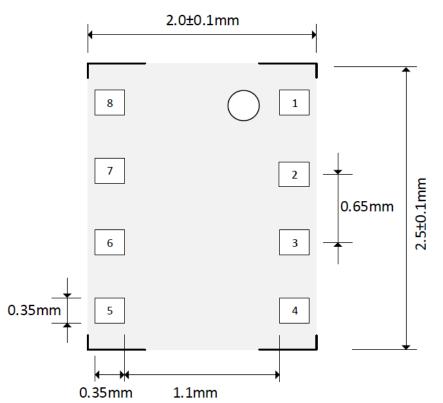
Figure 6. ICP-10111 Package Diagrams

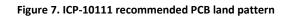


SYMBOLS	DIMENSIONS IN MILLIMETERS			
STIVIDULS	MIN.	NOM.	MAX.	
A	0.84	0.92	1.00	
A3		0.79 REF.		
b		0.35		
С		0.13 REF.		
E	1.90	2.00	2.10	
E1		1.85		
D	2.40	2.50	2.60	
D1		2.35		
e		0.65		
L	0.35	0.45	0.55	
L1	0.05	0.10	0.15	
L3	0.30	0.35	0.40	
S		0.10		

Table 17. ICP-10111 Package Dimensions

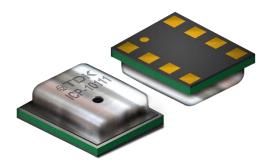
Recommended PCB land pattern for the ICP-10111:







### Product artwork for the ICP-10111:



Package Artwork: ICP-10111

## 8 PART NUMBER PART MARKINGS

The part number part markings for ICP-10111 devices are summarized below:

PART NUMBER	PART MARKING		
ICP-10111	P6		

Table 18. Part Number Part Markings

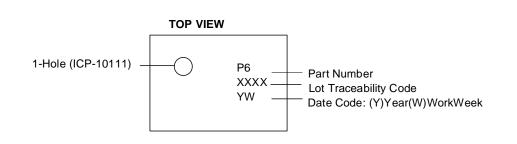


Figure 8. Part Number Part Markings for 2x2.5mm (ICP-10111)

# 9 TAPE & REEL SPECIFICATION

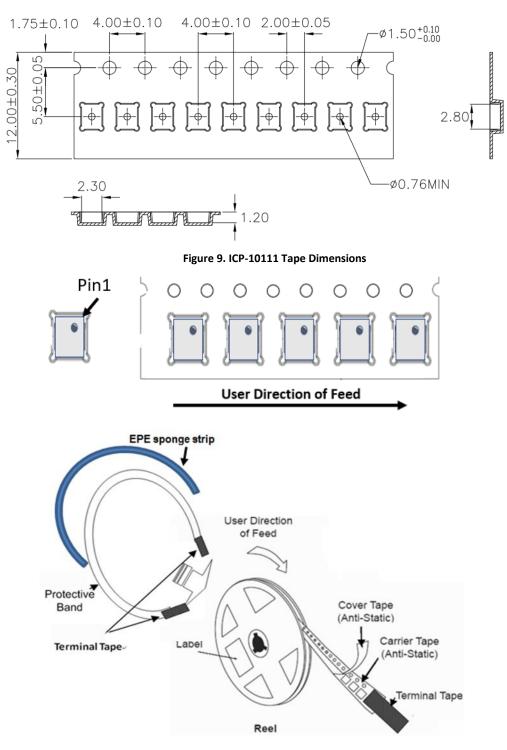


Figure 10. ICP-10111 Tape and Reel Drawing

# **10 ORDERING GUIDE**

PART	TEMP RANGE	PACKAGE BODY	PACKAGE LID	QUANTITY	PACKAGING
ICP-10111 <sup>+</sup>	–40°C to +85°C	2x2.5x0.92mm LGA-8L	1-Hole	10,000	13" Tape and Reel

<sup>†</sup>Denotes RoHS and Green-Compliant Package

### **11 REFERENCES**

Please refer to "InvenSense MEMS Handling Application Note (AN-IVS-0002A-00)" for the following information:

- Manufacturing Recommendations
  - Assembly Guidelines and Recommendations
  - PCB Design Guidelines and Recommendations
  - MEMS Handling Instructions
  - o ESD Considerations
  - o Reflow Specification
  - Storage Specifications
  - Package Marking Specification
  - Reel & Pizza Box Label
  - Packaging
  - o Representative Shipping Carton Label
- Compliance
  - o Environmental Compliance
  - o DRC Compliance
  - o Compliance Declaration Disclaimer



# **12 REVISION HISTORY**

Revision Date	Revision	Description
01/11/2017	0.1	Initial Release
01/17/2017	0.2	Updated Sections 6, 7
10/02/2020	1.0	Updated all sections
10/07/2020	1.1	Updated document title
04/06/2021	1.2	Updated Long-Term Drift specification (Table 3).
05/03/2021	1.3	Added MSL information (Cover Page); Added Tape & Reel Specification (Section 9).



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